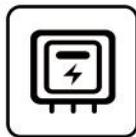




自主封測 品質把控 售後保障

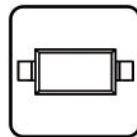
WEB | [WWW.TDSEMIC.COM](http://WWW.TDSEMIC.COM)



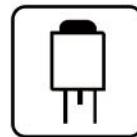
電源管理



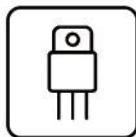
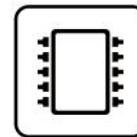
顯示驅動



二三極管 LDO穩壓器



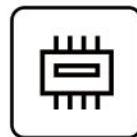
觸摸芯片



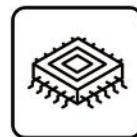
MOS管



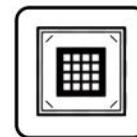
運算放大器



存儲芯片



MCU



串口通信

ES2JF

產品規格說明書

## ES2AF THRU ES2JF

### Surface Mount Superfast Recovery Rectifier

Reverse Voltage – 50 to 600 V

Forward Current –2 A

### FEATURES

- For surface mounted applications
- Low profile package
- Glass Passivated Chip Junction
- Superfast reverse recovery time
- Lead free in comply with EU RoHS 2011/65/EU directives

### MECHANICAL DATA

- Case: SMAF
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 27mg / 0.00095oz

### Absolute Maximum Ratings and Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameter	Symbols	ES2AF	ES2BF	ES2CF	ES2DF	ES2EF	ES2GF	ES2JF	Units		
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	50	100	150	200	300	400	600	V		
Maximum RMS voltage	$V_{RMS}$	35	70	105	140	210	280	420	V		
Maximum DC Blocking Voltage	$V_{DC}$	50	100	150	200	300	400	600	V		
Maximum Average Forward Rectified Current at $T_c = 125^\circ\text{C}$	$I_{F(AV)}$	2						A			
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load	$I_{FSM}$	50						A			
Maximum Forward Voltage at 2 A	$V_F$	1			1.25		1.68	V			
Maximum DC Reverse Current $T_a = 25^\circ\text{C}$ at Rated DC Blocking Voltage $T_a = 125^\circ\text{C}$	$I_R$	5 100						$\mu\text{A}$			
Typical Junction Capacitance at $V_R=4\text{V}$ , $f=1\text{MHz}$	$C_J$	30						$\text{pF}$			
Maximum Reverse Recovery Time <sup>(1)</sup>	$t_{rr}$	35						ns			
Typical Thermal Resistance <sup>(2)</sup>	$R_{\thetaJA}$ $R_{\thetaJC}$	65 20						$^\circ\text{C}/\text{W}$			
Operating and Storage Temperature Range	$T_J$ , $T_{stg}$	-55 ~ +150						$^\circ\text{C}$			

( 1 ) Measured with  $I_F = 0.5 \text{ A}$ ,  $I_R = 1 \text{ A}$ ,  $I_{rr} = 0.25 \text{ A}$ .

( 2 ) P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.

### PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



Top View  
Marking Code:  
ES2AF~ES2JF: ES2A~ES2J  
Simplified outline SMAF and symbol

## ES2AF THRU ES2JF

Fig.1 Reverse Recovery Time Characteristic And Test Circuit Diagram

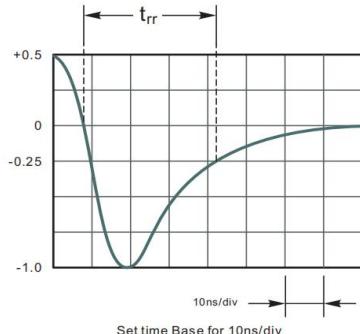
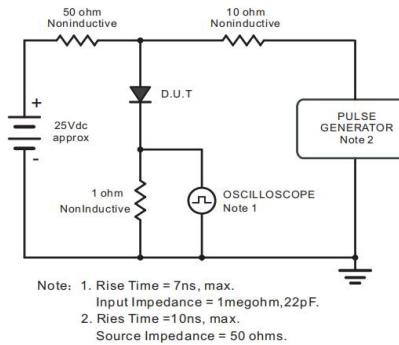


Fig.2 Maximum Average Forward Current Rating

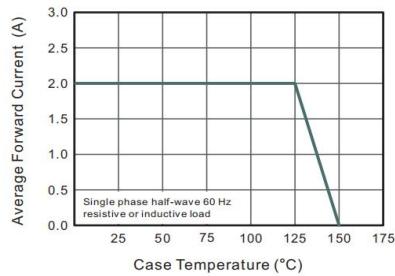


Fig.4 Typical Forward Characteristics

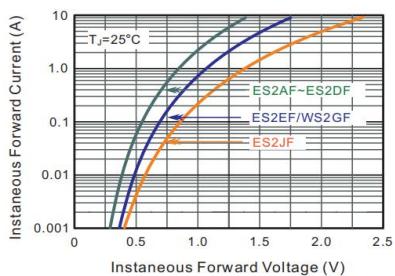


Fig.3 Typical Reverse Characteristics

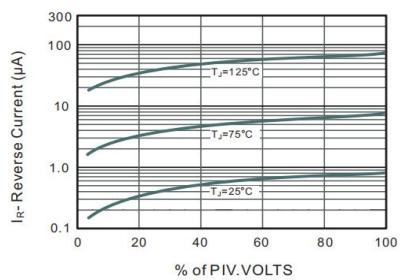


Fig.5 Typical Junction Capacitance

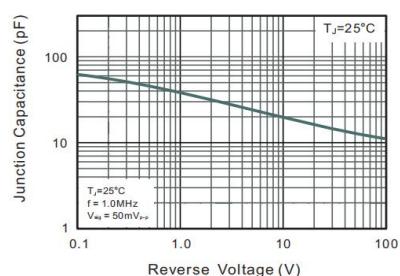
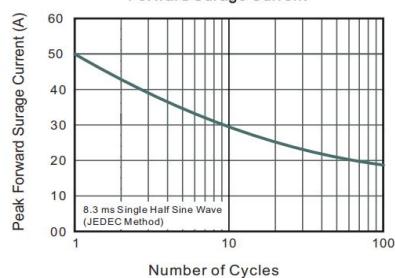


Fig.6 Maximum Non-Repetitive Peak Forward Surge Current

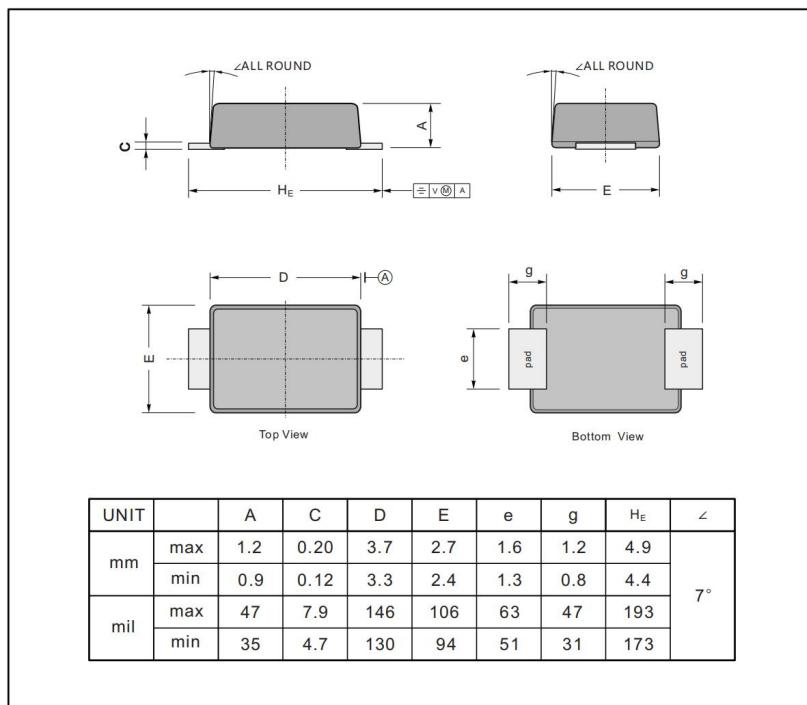


## ES2AF THRU ES2JF

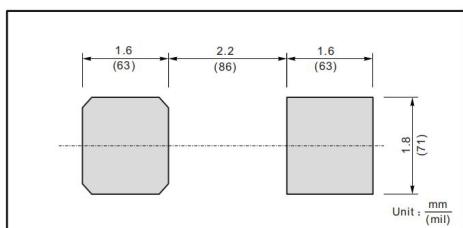
### PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SMAF



The recommended mounting pad size



Marking

Type number	Marking code
ES2AF	ES2A
ES2BF	ES2B
ES2CF	ES2C
ES2DF	ES2D
ES2EF	ES2E
ES2GF	ES2G
ES2JF	ES2J